LM710C

Voltage Comparators/Buffers

LM710C voltage comparator

general description

The LM710C is a high-speed voltage comparator intended for use as an accurate, low-level digital level sensor or as a replacement for operational amplifiers in comparator applications where speed is of prime importance. The circuit has a differential input and a single-ended output, with saturated output levels compatible with practically all types of integrated logic.

The device is built on a single silicon chip which insures low offset and thermal drift. The use of a minimum number of stages along with minoritycarrier lifetime control (gold doping) makes the circuit much faster than operational amplifiers in saturating comparator applications. In fact, the low stray and wiring capacitances that can be realized

with monolithic construction make the device difficult to duplicate with discrete components operating at equivalent power levels.

The LM710C is useful as a pulse height discriminator, a voltage comparator in high-speed A/D converters or a go, no-go detector in automatic test equipment. It also has applications in digital systems as an adjustable-threshold line receiver or an interface between logic types. In addition, the low cost of the unit suggests it for applications replacing relatively simple discrete component circuitry.

The LM710C is the commercial/industrial version of the LM710A. It is identical to the LM710A except that operation is specified over a 0° C to 70° C temperature range.



absolute maximum ratings

Positive Supply Voltage	14.0V
Negative Supply Voltage	-7.0V
Differential Input Voltage	±5.0V
Input Voltage	±7.0V
Power Dissipation (Note 1)	300 mW
Output Short Circuit Duration	10 sec
Operating Temperature Range	0°C to 70°C
Storage Temperature Range	–65°C to +150°C
Lead Temperature (soldering, 60 sec)	300°C

electrical characteristics (Note 2)

PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Offset Voltage	T _A = 25°C, R _S <200Ω V _{OUT} = 1.4V		1.6	5.0	mV
Input Offset Current	T _A = 25°C, V _{OUT} = 1.4V		1.8	5.0	μΑ
Input Bias Current	T _A = 25°C		16	25	μA
Voltage Gain	T _A = 25°C	1000	1500		
Output Resistance	Т _А = 25°С		200		Ω
. Output Sink Current	T _A = 25°C, ΔV _{IN} ≥5 mV V _{OUT} = 0	1.7	2.5		mA
Response Time (Note 3)			40		ns
Input Offset Voltage	R _s <200Ω			6.5	mV
Average Temperature	0°C≤T _A ≤70°C				
Coefficient of Input Offset Voltage	R _s ≤50Ω		5.0	20	μV <i>I</i> °C
Input Offset Current				7.5	μА
Average Temperature	25°C≤T _A ≤70°C		15	50	nA/°C
Coefficient of Input Offset Current	0°C≤T _A ≤25°C		24	100	nA/°C
Input Bias Current	$T_A = 0^{\circ}C$		25	40	μA
Input Voltage Range	V = −7.0V	±5.0			v
Differential Input Voltage Range		±5.0			V
Voltage Gain		800			
Positive Output Level	ΔV _{IN} ≥5 mV, 0≤I _{OUT} ≤5 mA	2.5	3.2	4.0	v
Negative Output Level	∆V _{IN} ≥5 mV	-1.0	-0.5	0	v
Output Sink Current	$\Delta V_{IN} \ge 5 \text{ mV}, V_{OUT} = 0.2 \text{V}$	1.6			mA
Positive Supply Current	-5V≤∆VIN≤5V, IOUT≤0			11	mA
Negative Supply Current			4.6	7.0	mA
Power Consumption	T _A = 70°C, Ι _{ΟUT} ≤0 -5V≤ΔV _{IN} ≤5V			170	mW

Note 1: Ratings apply for ambient temperatures to 70°C. Note 2: These specifications apply for V⁺ = 12.0V, V⁻ = 6.0V, 0°C \leq T_A \leq 70°C and for a logic threshold voltage of 1.5V at 0°C, 1.4V at 25°C and 1.2V at 70°C unless otherwise specified. Note 3: The response time specified (see definitions) is for a 100 mV input step with

5 mV overdrive.

typical performance characteristics







Input Bias Current

V⁺ = 12V V⁻ = -6.0V

30

20

10

0

0 10 20 30 40 50 60 70

INPUT BIAS CURRENT (μA)



Supply Current



Response Time For Various Input Overdrives

TEMPERATURE (°C)





TEMPERATURE (°C)



Common Mode Pulse Response



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